



DMN3112S

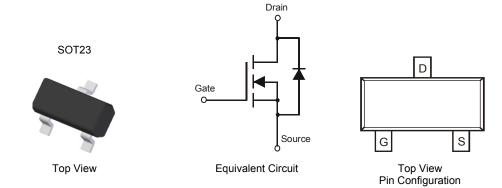
#### N-CHANNEL ENHANCEMENT MODE MOSFET

### **Features**

- Low On-Resistance:
  - 57mΩ @ V<sub>GS</sub> = 10V
  - 112mΩ @ V<sub>GS</sub> = 4.5V
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

### Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Weight: 0.008 grams (approximate)



#### Ordering Information (Note 5)

Part Number	Qualification	Case	Packaging
DMN3112S-7	Standard	SOT23	3000/Tape & Reel
DMN3112SQ-7	Automotive	SOT23	3000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

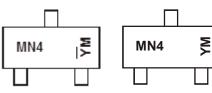
 See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/quality/product\_grade\_definitions/

5. For packaging details, go to our website at http://www.diodes.com/products/packages.html

## **Marking Information**



Chengdu A/T Site

Shanghai A/T Site

MN4 = Product Type Marking Code YM = Date Code Marking for SAT (Shanghai Assembly/ Test site)  $\overline{Y}M$  = Date Code Marking for CAT (Chengdu Assembly/ Test site) Y or  $\overline{Y}$  = Year (ex: A = 2013) M = Month (ex: 9 = September)

Date Code Key

Year	2008	2009	20	10	2011	2012	2013	2014	20	15	2016	2017
Code	V	W	>	(	Y	Z	A	В	(	C	D	Е
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



## Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain Source Voltage		V <sub>DSS</sub>	30	V
Gate-Source Voltage		V <sub>GSS</sub>	±20	V
Drain Current (Note 6)	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	ID	5.8 4.2	А
Drain Current (Note 6)	Pulsed	I <sub>DM</sub>	20	А
Body-Diode Continuous Current (Note 6)		Is	2.0	A

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 6)	PD	1.4	W	
Thermal Resistance, Junction to Ambient @T <sub>A</sub> = +25°C (Note 6)	$R_{ heta}$ JA	90	°C/W	
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C	

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

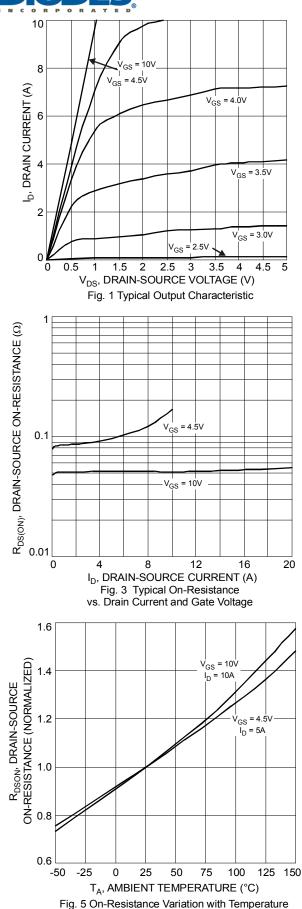
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)			•	•			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	30	_	_	V	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250µA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	800	nA	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V	
Gate-Body Leakage	I <sub>GSS</sub>	_	_	±80 ±800	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$ $V_{GS} = \pm 25V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	1.3	1.9	2.2	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
Static Drain-Source On-Resistance	R <sub>DS (ON)</sub>	_	47 92	57 112	mΩ	V <sub>GS</sub> = 10V, I <sub>D</sub> = 5.8A V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 4.2A	
Forward Transconductance	Y <sub>fs</sub>		4.7	_	S	V <sub>DS</sub> = 5V, I <sub>D</sub> = 4.2A	
Source-Drain Diode Forward Voltage	V <sub>SD</sub>		0.78	1.1	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = 2.0A	
DYNAMIC CHARACTERISTICS (Note 8)						·	
Input Capacitance	C <sub>iss</sub>	_	268	_	pF		
Output Capacitance	C <sub>oss</sub>	_	73	_	pF	V <sub>DS</sub> = 5V, V <sub>GS</sub> = 0V f = 1.0MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>		50	—	pF		

Notes: 6. Device mounted on FR-4 PCB. t  $\leq$ 5 sec.

7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to production testing.





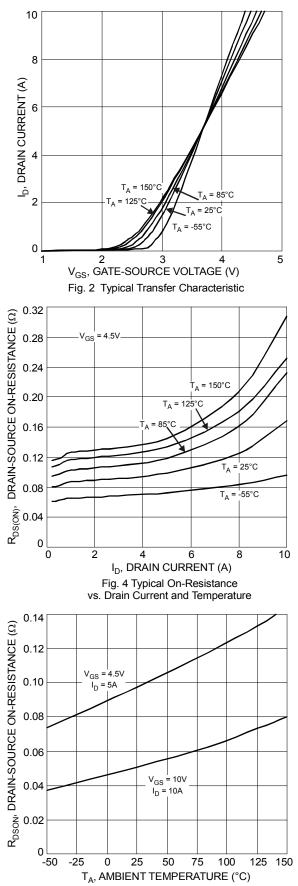
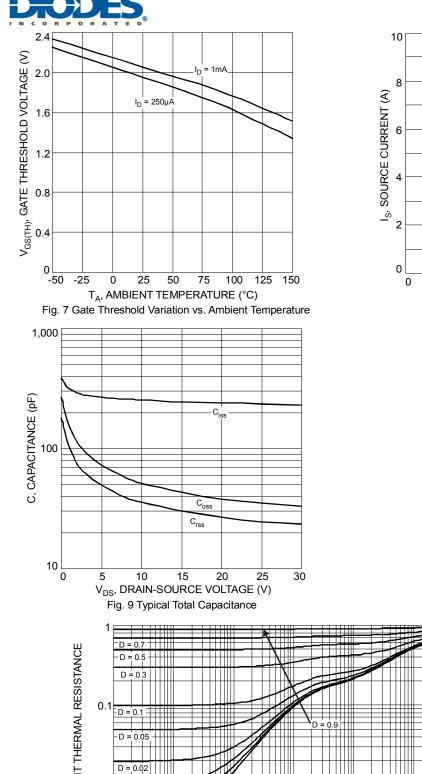
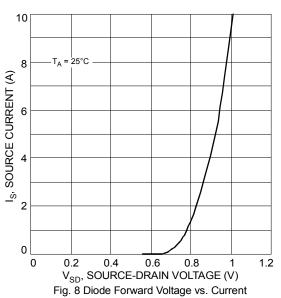
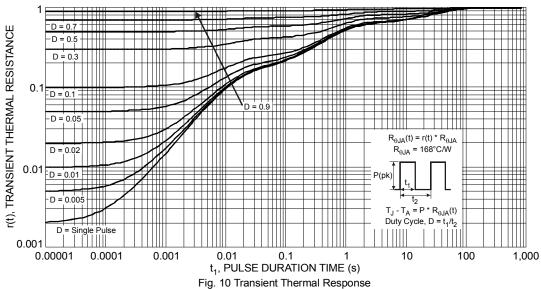


Fig. 6 On-Resistance Variation with Temperature





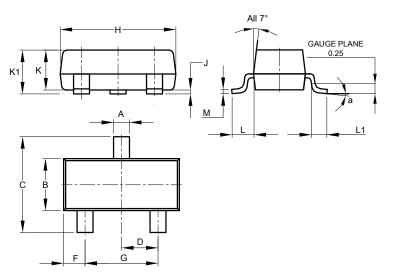






## Package Outline Dimensions

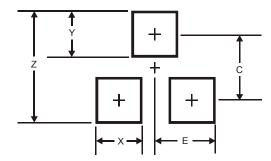
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



	SOT23						
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
К	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
Μ	0.085	0.150	0.110				
α	8°						
All	All Dimensions in mm						

## Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35



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